Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.470 inches

Overall Height:

0.142 inches

Overall Width:

0.251 inches

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

3.5 peak gate turn-off voltage

Power Rating Per Characteristic:

2.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius junction

Test Data Document:

14399-353-3729 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 ribbon

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A110a0